

TECHNICAL DATA DATA SHEET 4505, REV. -

POWER SCHOTTKY RECTIFIER Low Reverse Leakage

Applications:

• Switching Power Supply • Converters • Free-Wheeling Diodes • Polarity Protection Diode

Features:

- Ultra Low Reverse Leakage Current
- Soft Reverse Recovery at Low and High Temperature
- Low Forward Voltage Drop
- Low Power Loss, High Efficiency
- High Surge Capacity
- Guard Ring for Enhanced Durability and Long Term Reliability
- Guaranteed Reverse Avalanche Characteristics

Maximum Ratings:

Characteristics	Symbol	Condition	Max.	Units
Peak Inverse Voltage	V_{RWM}	-	100	V
Max. Average Forward	I _{F(AV)}	50% duty cycle, rectangular	15	Α
Current		wave form		
Max. Peak One Cycle Non-	I _{FSM}	8.3 ms, half Sine wave	280	Α
Repetitive Surge Current		(per leg)		
Non-Repetitive Avalanche	E _{AS}	$T_J = 25 ^{\circ}\text{C}, I_{AS} = 1.3 \text{A},$	27	mJ
Energy		L = 40mH (per leg)		
Repetitive Avalanche	I _{AR}	I _{AS} decay linearly to 0 in 1 μs	1.3	Α
Current		f limited by T _J max V _A =1.5V _R		
Thermal Resistance	R_{thJC}	Per Package	0.85	°C/W
Max. Junction Temperature	TJ	-	-65 to +200	°C
Max. Storage Temperature	T _{stg}	-	-65 to +200	°C

Electrical Characteristics:

Characteristics	Symbol	Condition	Max.	Units
Max. Forward Voltage Drop	V_{F1}	@ 15A, Pulse, T _J = 25 °C	0.84	V
		(per leg) measured at the leads		
	V_{F2}	@ 15A, Pulse, T _J = 125 °C	0.68	V
		(per leg) measured at the leads		
Max. Reverse Current	I _{R1}	@V _R = 100V, Pulse,	0.35	mA
		T _J = 25 °C (per leg)		
	I _{R2}	@V _R = 100V, Pulse,	8.0	mA
		T _J = 125 °C (per leg)		
Max. Junction Capacitance	C _T	$@V_R = 5 \text{ V}, T_C = 25 ^{\circ}\text{C}$	500	pF
		$f_{SIG} = 1 MHz,$		
		$V_{SIG} = 50 \text{mV (p-p) (per leg)}$		

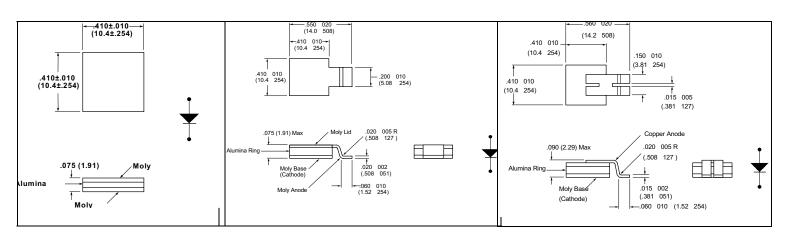
Due to the nature of the 100V Schottky devices, some degradation in t_{rr} performance at high temperatures should be expected, unlike conventional lower voltage Schottkys.

^{• 221} West Industry Court ☐ Deer Park, NY 11729-4681 ☐ (631) 586-7600 FAX (631) 242-9798 •

[•] World Wide Web Site - http://www.sensitron.com • E-Mail Address - sales@sensitron.com •

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Mechanical Dimensions: in inches / mm



SHD-3 SHD-3A SHD-3B

10¹ 10¹ 200℃

125℃

Typical Forward Characteristics

175℃

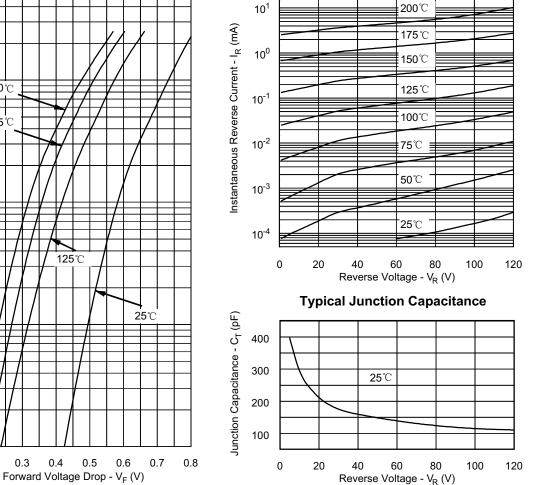
Instantaneous Forward Current - I_F (A)

10⁰

10⁻¹

10⁻² 0.1

Typical Reverse Characteristics



Vf Curves shown are for die only.

0.3

0.4

0.5

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TECHNICAL DATA

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